

## Optocoupler with Photodarlington Output

### Description

The TCLD10.. Series consists of a darlington phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead SO6L package. The elements are mounted on one leadframe using a **coplanar technique**, providing a fixed distance between input and output for highest safety requirements.



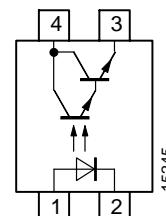
15231

### Applications

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- For appl. class I – IV at mains voltage  $\leq 300$  V
- For appl. class I – III at mains voltage  $\leq 600$  V  
according to VDE 0884, table 2, suitable for:

**Switch-mode power supplies, line receiver, computer peripheral interface, microprocessor system interface.**



15245

### VDE Standards

These couplers perform safety functions according to the following equipment standards:

- **VDE 0884**  
Optocoupler for electrical safety requirements  
(will be replaced by IEC 747-5-1.2.3)
- **IEC 950/EN 60950**  
Office machines (applied for reinforced isolation for mains voltage  $\leq 400$  V<sub>RMS</sub>)
- **VDE 0804**  
Telecommunication apparatus and data processing
- **IEC 65**  
Safety for mains-operated electronic and related household apparatus



0884

### Order Instruction

Ordering Code	CTR Ranking	Remarks
TCLD1000	>600%	4 Pin = Single channel

## Features

### Approvals:

- **BSI:** BS EN 41003, BS EN 60095 (BS 415),  
BS EN 60950 (BS 7002),  
Certificate number 7081 and 7402
- Underwriters Laboratory (UL) 1577 recognized,  
file number E-76222 – Double Protection
- **CSA (C-UL)** 1577 recognized  
file number E- 76222 - Double Protection
- **VDE** 0884, Certificate number 132473

### VDE 0884 related features:

- Rated impulse voltage (transient overvoltage)  
 $V_{IOTM} = 8 \text{ kV peak}$
- Isolation test voltage  
(partial discharge test voltage)  $V_{pd} = 1.6 \text{ kV}$
- Rated isolation voltage (RMS includes DC)  
 $V_{IOWM} = 600 \text{ V}_{\text{RMS}}$  (848 V peak)
- Rated recurring peak voltage (repetitive)  
 $V_{IORM} = 600 \text{ V}_{\text{RMS}}$

- Creepage current resistance according  
to VDE 0303/IEC 112  
**Comparative Tracking Index: CTI**  $\geq 175$
- Thickness through insulation  $\geq 0.75 \text{ mm}$
- Creepage distance  $> 8 \text{ mm}$
- Tested acc. 60950: Am4: 1997 clause 2.9.6.

### General features:

- Low profile package
- Darlington output
- Isolation materials according to UL94-VO
- Pollution degree 2 (DIN/VDE 0110 / resp. IEC 664)
- Climatic classification 55/100/21 (IEC 68 part 1)
- Special construction:  
Therefore, extra low coupling capacity of  
typical 0.2 pF, high **Common Mode Rejection**
- Low temperature coefficient of CTR
- Coupling System W

## Absolute Maximum Ratings

### Input (Emitter)

Parameter	Test Conditions	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10 \mu\text{s}$	$I_{FSM}$	1.5	A
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$

### Output (Detector)

Parameter	Test Conditions	Symbol	Value	Unit
Collector emitter voltage		$V_{CEO}$	35	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector current		$I_C$	80	mA
Collector peak current	$t_p/T = 0.5, t_p \leq 10 \text{ ms}$	$I_{CM}$	100	mA
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	150	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$

### Coupler

Parameter	Test Conditions	Symbol	Value	Unit
Isolation test voltage (RMS)		$V_{IO}$	5	kV
Total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_{tot}$	250	mW
Operating ambient temperature range		$T_{amb}$	-40 to +100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	-40 to +100	$^\circ\text{C}$
Soldering temperature		$T_{sd}$	235	$^\circ\text{C}$

**Electrical Characteristics ( $T_{amb} = 25^\circ C$ )**
**Input (Emitter)**

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Forward voltage	$I_F = \pm 50 \text{ mA}$	$V_F$		1.25	1.6	V
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_j$		50		pF

**Output (Detector)**

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	35			V
Emitter collector voltage	$I_E = 100 \mu\text{A}$	$V_{ECO}$	7			V
Collector emitter cut-off current	$V_{CE} = 20 \text{ V}, I_f = 0, E = 0$	$I_{CEO}$			100	nA

**Coupler**

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 100 \Omega$	$f_c$		10		kHz
Coupling capacitance	$f = 1 \text{ MHz}$	$C_k$		0.3		pF

**Current Transfer Ratio (CTR)**

Parameter	Test Conditions	Type	Symbol	Min.	Typ.	Max.	Unit
$I_C/I_F$	$V_{CE} = 2 \text{ V}, I_F = 1 \text{ mA}$	TCLD1000	CTR	6.0	8.0		

### Maximum Safety Ratings (according to VDE 0884) see figure 1

This optocoupler is suitable for safe electrical isolation only within the safety ratings.  
Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

#### Input (Emitter)

Parameters	Test Conditions	Symbol	Value	Unit
Forward current		$I_{si}$	130	mA

#### Output (Detector)

Parameters	Test Conditions	Symbol	Value	Unit
Power dissipation	$T_{amb} \leq 25^\circ C$	$P_{si}$	265	mW

#### Coupler

Parameters	Test Conditions	Symbol	Value	Unit
Rated impulse voltage		$V_{IOTM}$	8	kV
Safety temperature		$T_{si}$	150	°C

### Insulation Rated Parameters (according to VDE 0884)

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Partial discharge test voltage – Routine test	100%, $t_{test} = 1$ s	$V_{pd}$	1.6			kV
Partial discharge test voltage – Lot test (sample test)	$t_{Tr} = 60$ s, $t_{test} = 10$ s, (see figure 2)	$V_{IOTM}$	8			kV
		$V_{pd}$	1.3			kV
Insulation resistance	$V_{IO} = 500$ V	$R_{IO}$	$10^{12}$			Ω
	$V_{IO} = 500$ V, $T_{amb} = 100^\circ C$	$R_{IO}$	$10^{11}$			Ω
	$V_{IO} = 500$ V, $T_{amb} = 150^\circ C$ (construction test only)	$R_{IO}$	$10^9$			Ω

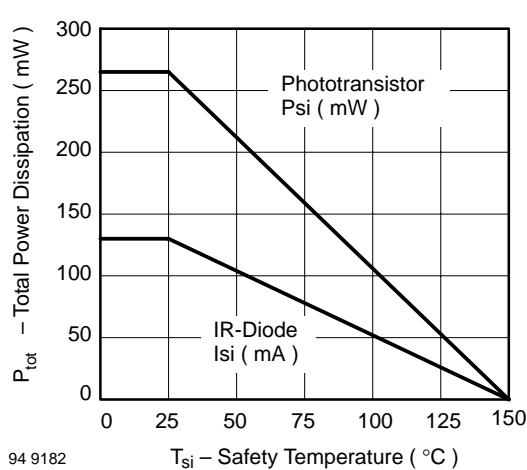


Figure 1. Derating diagram

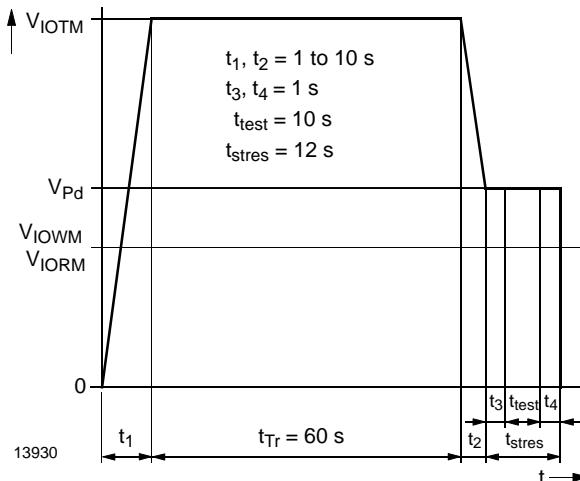


Figure 2. Test pulse diagram for sample test according to DIN VDE 0884

## Switching Characteristics

Parameter	Test Conditions	Symbol	Typ.	Unit
Rise time	$V_{CE} = 2 \text{ V}$ , $I_C = 10 \text{ mA}$ , $R_L = 100 \Omega$ (see figure 1)	$t_r$	300	$\mu\text{s}$
Turn-off time		$t_{off}$	250	$\mu\text{s}$

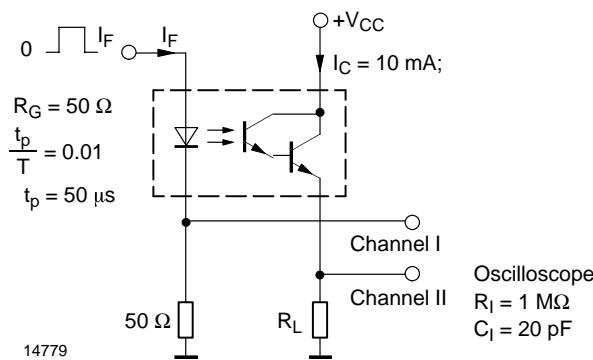


Figure 1. Test circuit, non-saturated operation

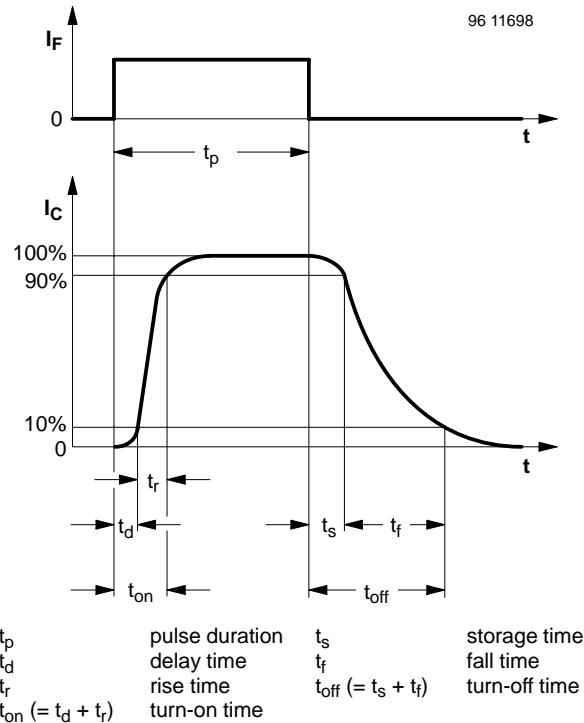


Figure 2. Switching times

## Typical Characteristics ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

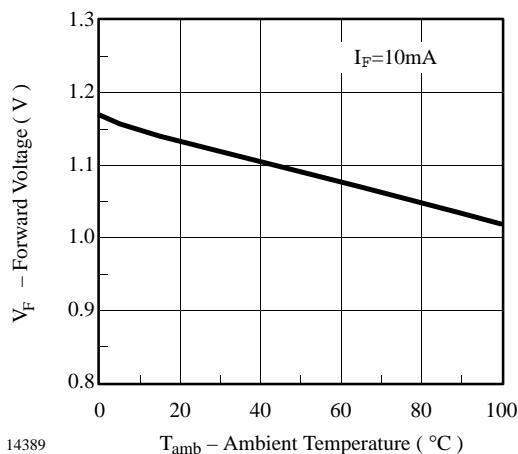


Figure 3. Forward Voltage vs. Ambient Temperature

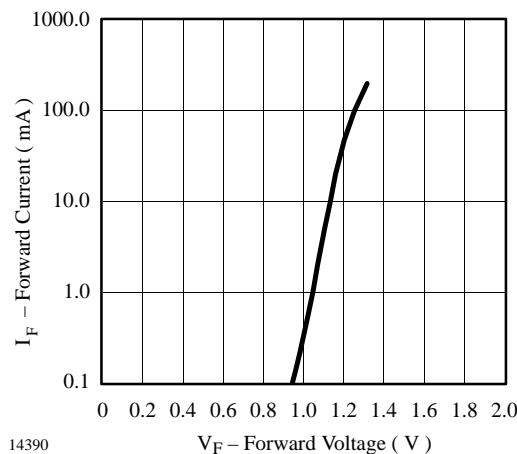
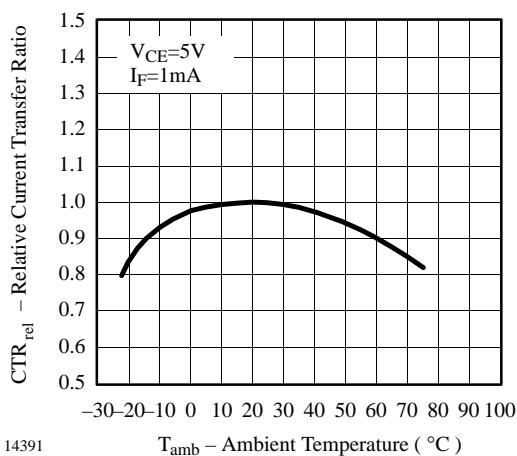


Figure 4. Forward Current vs. Forward Voltage

# TCLD10.. Series

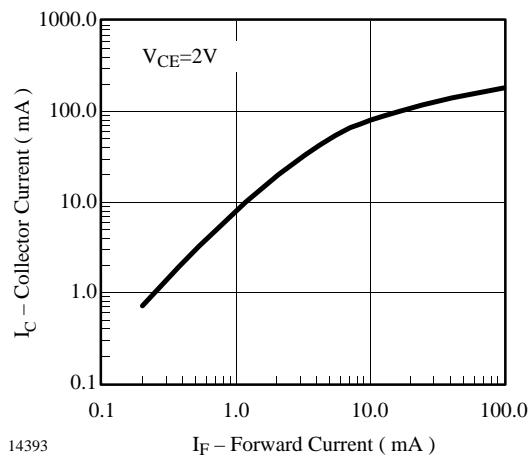
Vishay Telefunken



14391

$T_{amb}$  – Ambient Temperature ( °C )

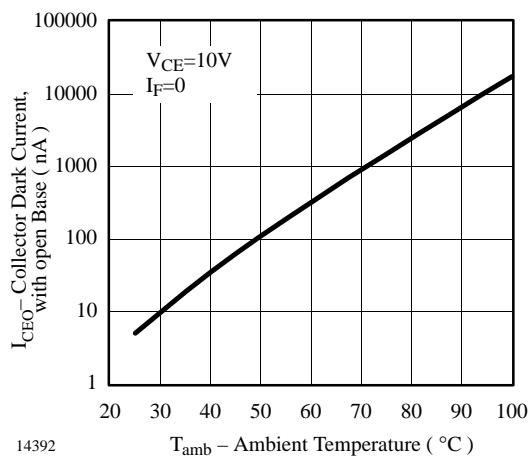
Figure 5. Relative Current Transfer Ratio vs. Ambient Temperature



14393

$I_F$  – Forward Current ( mA )

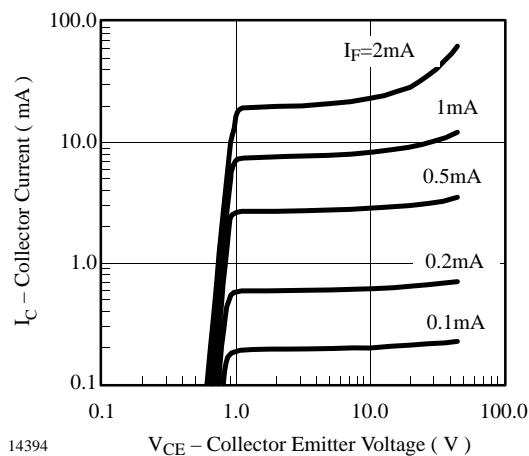
Figure 7. Collector Current vs. Forward Current



14392

$T_{amb}$  – Ambient Temperature ( °C )

Figure 6. Collector Dark Current vs. Ambient Temperature



14394

$V_{CE}$  – Collector Emitter Voltage ( V )

Figure 8. Collector Current vs. Collector Emitter Voltage

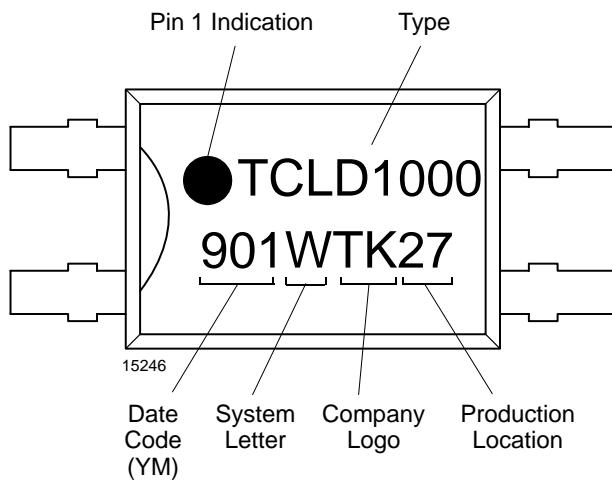
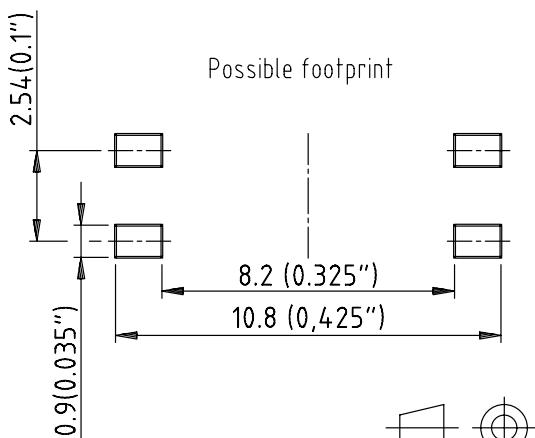
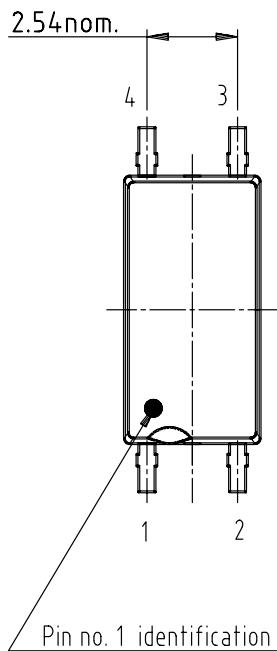
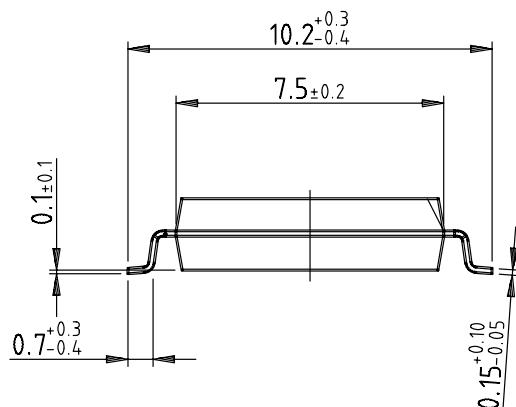
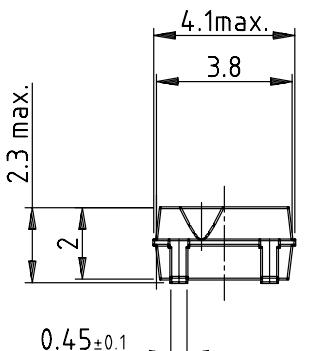


Figure 9. Marking example

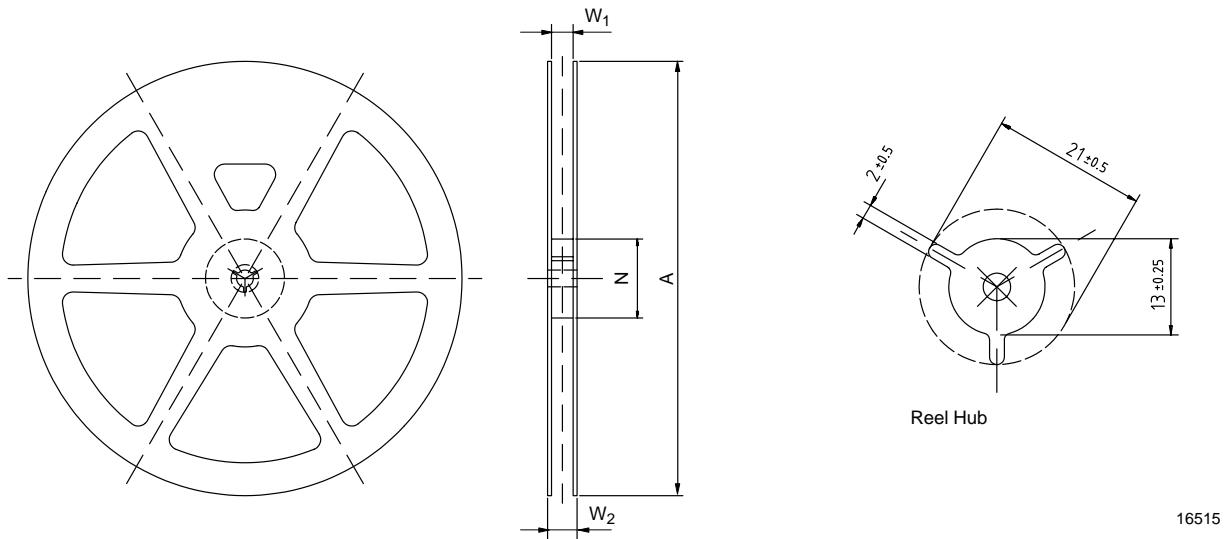
**Dimensions of TCLD10.. in mm**


technical drawings  
according to DIN  
specifications

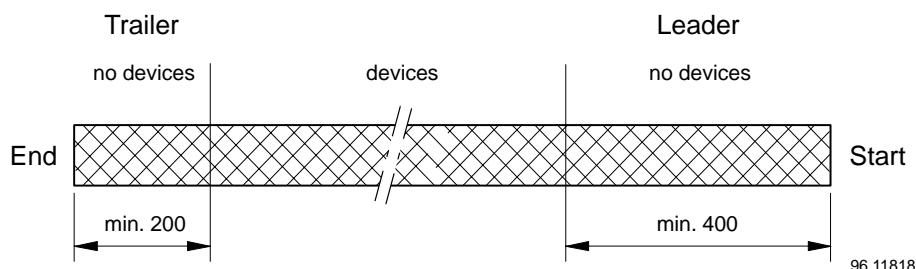
Drawing-No.: 6.544-5331.01-4

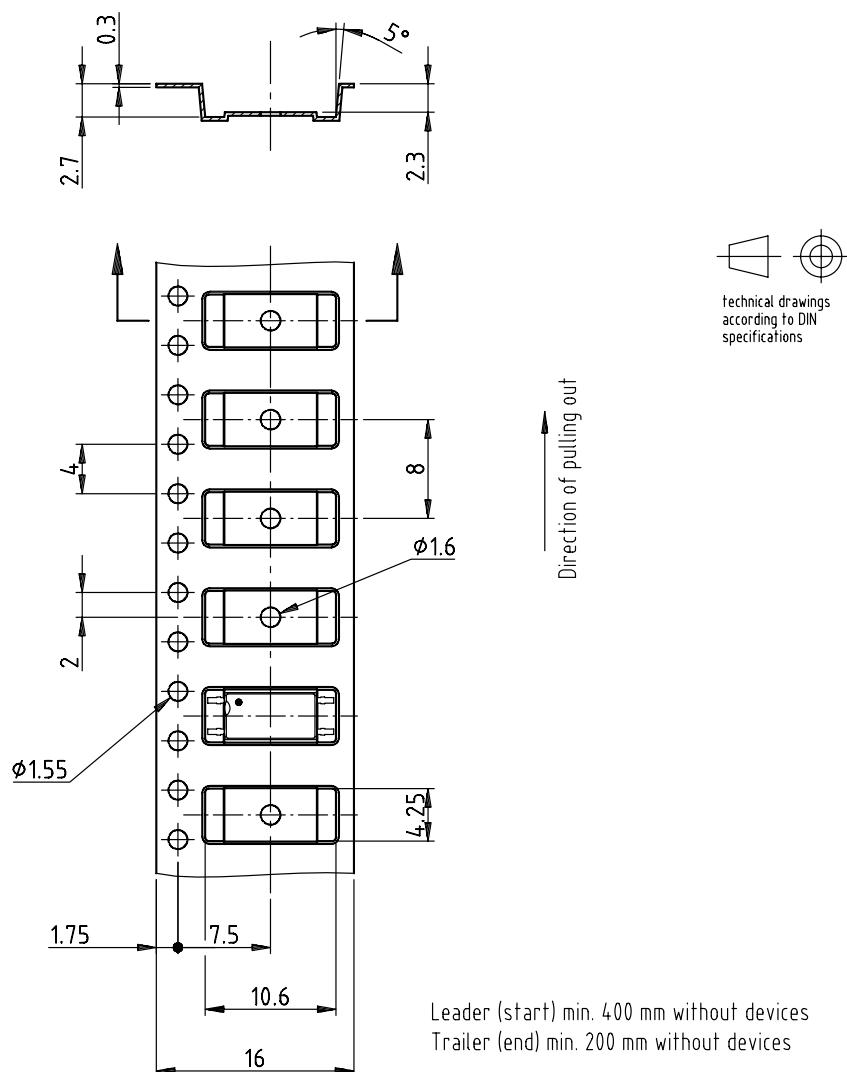
Issue: 1; 04.04.00

15243

**Dimensions of Reel in mm**

Version	Tape Width	A	N	W <sub>1</sub>	W <sub>2 max</sub>
G	16	330 ± 1	100 ± 1.5	16.4 + 2	22.4

**Dimensions of Leader and Trailer in mm**

**Dimensions of Tape in mm**


Issue: 1; 22.11.00

Drawing refers to following types: TCLT 1...

16516

### Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**Vishay Semiconductor GmbH** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany  
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423